## NSN 5961-00-472-3541

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.535 inches

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-63

### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

#### Hermetically sealed case

#### **Overall Width Across Flats:**

0.875 inches

## Thread Size:

0.312 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 20.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

60.00 amperes source cutoff current and 15.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

300.0 watts small-signal input power, common-collector absolute

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

28009-16601887 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

3 tab, solder lug

## Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

